T I	Hits	Search Text	DB	Time stamp
Number				
	2967	((438/207) or (438/218) or (438/219) or (438/221) or (438/404) or (438/404) or (438/404) or (438/424)).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/11/13
-		(((438/207) or (438/218) or (438/219) or (438/221) or (438/401) or (438/404) or (438/424)).CCLS.) and (cmos or (complementary adj metal adj oxide adj semiconductor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/11/13   21:14 
-     	387	[(((438/207) or (438/218) or (438/219) or (438/221) or (438/201) or (438/404) or (438/424). CCLS.) and (cmos or (complementary adj metal adj oxide adj semiconductor))) and ((trench same isolation) or sti or (shallow adj trench adj isolation))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/13
-       	256	(((438/207) or (438/218) or (438/219) or (438/221) or (438/401) or (438/404) or (438/424).CCLS.) and (cmos or (complementary adj metal adj oxide adj semiconductor)) and (trench same isolation) or st or (shallow adj trench adj isolation)) and polysilicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/13
		[((((1438/207) or (438/218) or (438/219) or (438/221) or (438/401) or (438/404) or (438/404) or (438/404). CCLS.) and (cmos or (complementary adj metal adj oxide adj semiconductor)) and ((trench same isolation) or sti or (shallow add trench adj isolation))) and polysilicon) and (thick or thickness) and (depth or deep)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/13   21:16   
		[((((((438/207) or (438/218) or (438/219) or (438/219) or (438/24) or (438/401) or (438/404) or (438/404) or (438/404)).CCLS.) and (cmos or (complementary adj metal adj oxide adj semiconductor)) and ((trench same jisolation) or sti or (shallow add trench adj isolation))) and polysilicon) and (thick or thickness) and (depth or deep)) and (cmp or (chemical adj mechanical adj planariz55))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/13
	1327	(EVANS same DAVID) or (HSU same (SHENG or TENG)) or (ULRICH same BRUCE) or (TWEET same DOUGLAS)	USPAT;   US-PGPUB;   EPO; JPO;   DERWENT;   IBM TDB	2003/11/13
i		(EVANS same DAVID) or (HSU same (SHENG or TENG)) or (ULRICH same BRUCE) or (TWEET same DOUGLAS) or (STECKER same LISA)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/13   21:23 
-   	98	((EVANS same DAVID) or (HSU same (SHENG or TENG)) or (ULRICH same BRUCE) or (TWEET same DOUGLAS) or (STECKER same LISA)) and CMOS	USPĀT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/13
-     	į	(((EVANS same DAVID) or (HSU same (SHENG or TENG) or (URIGH same BRUCE) or (TWEET same DOUGLAS) or (STECKER same LISAN) and CMOS) and ((trench same isolation) or sti or (shallow adj trench	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/13   21:23 
	33 <sup> </sup>   	adj isolation))  ((((EVANS same DAVID) or (HSU same (SHENG or TENG)) or (ULRICH same BBUCE) or (TWEET same DOUGLAS) or (STECKER same LISA)) and CMOS) and ((trench same isolation) or sti or (shallow adj trench adj isolation))) and polysilicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/13 21:24

	19 ((((EVANS same DAVID) or (HSU same (SHENG or TENG)) or (ULRICH same BRUCE) or (WWEST same DOUGLAS) or (STECKER same LISA)) and (Utrench same isolation) or sti or (shillow ad) trench adj isolation))) and polysilicon) and (comp or (chemical ad) mechanical ad)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	72003/11/13   21:24   	-
	planariz\$5))  planariz\$5)  ((((((1438/207) or (438/218) or (438/219) or (438/201)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/13	